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> Substitute for form 1449/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT

Date Submitted: November 20, 2006

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Complete if Known 10/751,943 **Application Number** 1/7/2004 Filing Date Lars Ivar SAMUELSON **First Named Inventor** 2891 Art Unit Examiner Name Matthew W. SUCH **Attorney Docket Number** 077424-0105

			U.S. PATENT DO	CUMENTS	·
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